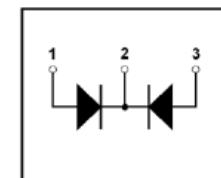
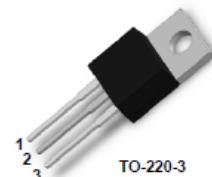


FAST RECOVER DIODE

Features

- 600V,16A
- Soft Recovery
- Operation Temperature <150°C
- Planar Construction



Applications

- Freewheeling,Snubber,Clamp
- Inversion Welder
- PFC
- Plating Power Supply
- Ultrasonic Cleaner and Welder
- Converter & Chopper
- UPS

Absolute Maximum Ratings

Symbol	Parameter	Value	Units
V_R	Maximum D.C. Reverse Voltage	600	V
V_{RRM}	Maximum Repetitive Reverse Voltage	600	V
$I_{F(AV)}$	Continuous Forward Current Per Diode ($T_c=100\text{ }^\circ\text{C}$)	8	A
	Continuous Forward Current Per Package($T_c=100\text{ }^\circ\text{C}$)	16	A
I_{FRMS}	RMS Forward Current ($T_c=100\text{ }^\circ\text{C}$)	12	A
I_{FSM}	Non-Repetitive Surge Forward Current	80	A
P_D	Power Dissipation	42	W
T_J	Operating Junction Temperature Range	-55 to +175	$^\circ\text{C}$
T_{STG}	Storage Temperature Range	-55 to +175	$^\circ\text{C}$
R_{thJC}	Thermal Resistance	3	$^\circ\text{C}/\text{W}$

Electrical Characteristics ($T_C=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
V_F	Diode Forward Voltage	$I_F=8\text{A} T_C=25^\circ\text{C}$		1.3	1.7	V
	Diode Forward Voltage	$I_F=8\text{A} T_C=125^\circ\text{C}$		1.0	1.5	V
IR	Instantaneous reverse current	$V_R=600\text{V}$			10	μA
I_{RRM}	Diode peak Reverse Recovery Current	$I_F=1\text{A}$		1.2		A
	Diode Reverse Recovery Time	$dif/dt=200\text{A}/\mu\text{s}$		30		ns
Q_{RR}	Diode Reverse Recovery Charge	$V_R=30\text{V}$		20		nC
	Diode peak Reverse Recovery Current	$I_F=8\text{A}$,		5.2		A
trr	Diode Reverse Recovery Time	$dif/dt=200\text{A}/\mu\text{s}$		55		ns
	Diode Reverse Recovery Charge	$V_R=300\text{V}$		170		nC

Fig.1 Forward Current vs Forward Voltage

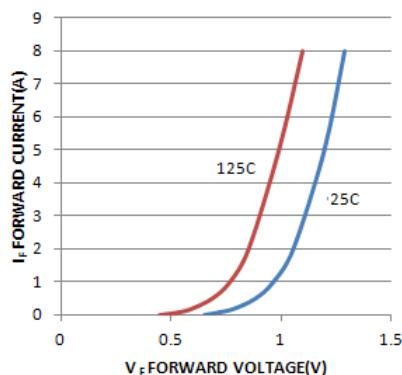


Fig.2 Reverse Current vs Reverse Voltage

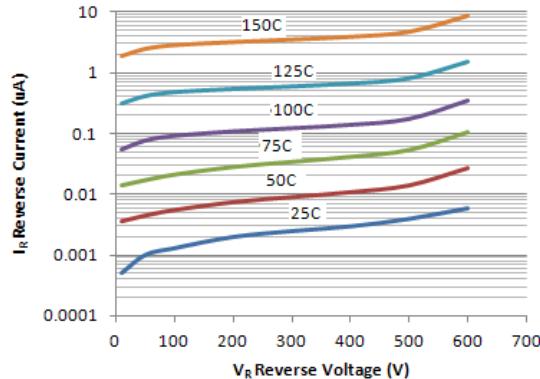


Fig.3 trr Test Circuit

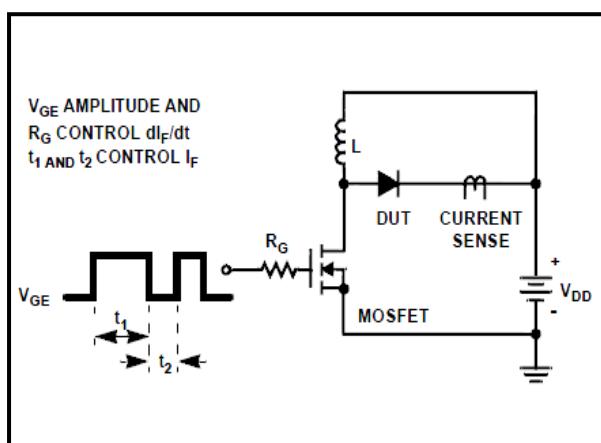


Fig.4 trr Waveforms and Definitions

